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Relationship between crystal structure and microwave dielectric properties of melilite-type ceramic

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Abstract

Crystal structure–microwave dielectric property relations in the melilite-type $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ ceramics were investigated in this study. The formation of a secondary phase was not detected over the whole composition range. Also, the lattice parameter, a, of the solid solutions decreased linearly with increasing the composition x, while the lattice parameter, c, was increased by the Zn substitution for Mg. Also, the covalency of the Mg–O bond increased from 26 to 35% in the composition range of 0–0.75. Moreover, the covalency of the Zn–O bond increased in the composition range of 0.25–1, while that of Si–O bonds in the SiO₄ tetrahedron remained approximately constant over the whole composition range. The dielectric constants (ϵ_r) of the solid solutions were on the order of approximately 7.5, and the quality factors ($Q\cdot f$) of the solid solutions increased with increasing the composition x. The temperature coefficient of resonant frequency (τ_f) of the solid solutions varied from -62 to -74 ppm/°C with increasing the composition x; therefore, the Zn substitution for Mg was not effective in improving the τ_f value in this system.

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1. Introduction

In the commercial applications such as the high-frequency systems, the silicates have been reported as the attractive candidates for use. A low dielectric constant (ε_r), a high quality factor ($Q \cdot f$) and a near zero temperature coefficient of resonant frequency (τ_f) are generally required for these applications. The forsterite (Mg₂SiO₄) ceramic is well known to have the microwave dielectric properties: $\varepsilon_r = 7.8$, $Q \cdot f = 240,000\,\text{GHz}$ and $\tau_f = -67\,\text{ppm/}^\circ\text{C}$. However, the continuous development of wireless communication technology will rely upon the identification of new dielectric ceramics with the appropriate microwave dielectric properties as described above.

In recent work, it has been reported that the several mixed alkaline earth and transition metal silicates, which have the melilite-type crystal structure with space group of C12/c1 (no. 15), are represented as $M_2M'Si_2O_7$, where M is an alkaline earth and M' is a transition metal.^{4,5} However, the microwave dielectric properties of these compounds have not been reported to date. Thus, in order to clarify the microwave dielectric prop-

erties of $Ba_2MgSi_2O_7$ ceramic, the $Ba_2MgSi_2O_7$ ceramic was synthesized, the Zn substitution for Mg was performed, and the crystal structure–microwave dielectric property relationship of the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions were investigated in this study.

2. Experimental method

High-purity (>99.9%) BaCO₃, MgO, ZnO and SiO₂ powders weighed on the basis of the their stoichiometric composition were mixed and calcined at $1000\,^{\circ}\text{C}$ for $10\,\text{h}$ in air. These calcined powders were milled and mixed with a polyvinyl alcohol, and then pressed into a pellet of 12 mm in diameter and 7 mm in thickness under the pressure of $100\,\text{MPa}$. Subsequently, these pellets were sintered at the various temperatures ranging from 1300 to $1350\,^{\circ}\text{C}$ for $10\,\text{h}$ in air. The crystalline phases were identified by X-ray powder diffraction (XRPD). The lattice parameters and the crystal structures of the samples were refined by using Rietveld analysis (RIETAN).^{6,7} The dielectric constants and the quality factors were measured by the Hakki–Coleman method.⁸ The $\tau_{\rm f}$ values were determined from the differences in the resonant frequencies obtained at the temperatures of 20 and $80\,^{\circ}\text{C}$.

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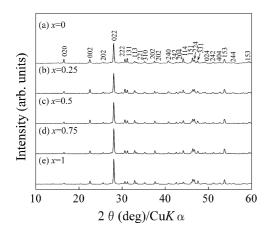


Fig. 1. XRPD patterns of $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions sintered at various temperatures for 10 h in air.

3. Results and discussion

Fig. 1 shows the XRPD patterns of $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions sintered at various temperatures for 10 h in air. From the XRPD results of Zn-substituted Ba₂($Mg_{1-x}Zn_x$)Si₂O₇ solid solutions, the samples over the whole composition range showed a single phase, which was a monoclinic crystal structure with C12/c1 space group. In the crystal structure of Ba₂MgSi₂O₇ ceramic, the crystal structure consists of MgO₄ tetrahedron which share their oxygen atoms with those of the $[Si_2O_7]^{6-}$, and the two-dimensional extended layers are separated by the Ba atoms, as shown in Fig. 2. Moreover, the peak shifts to smaller angle of 2θ are recognized with increasing the composition x as shown in Fig. 1. Thus, it was expected that the lattice parameters and the unit cell volume were varied by the Zn substitution for Mg; therefore, the lattice parameters and the unit cell volume of the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions were refined in terms of the Rietveld analysis, and the results are shown in Fig. 3. A linear dependence of the lattice parameters in the solid solutions was observed; the lattice parameter, a, decreased linearly with increasing the composition x, while the lattice parameter, c, was increased by the Zn substitution for Mg. Furthermore, no variations in the lattice parameter, b, of the solid solutions was observed in the composition range of 0–1. From the results of these variations in the lattice parameters, the Ba₂(Mg_{1-x}Zn_x)Si₂O₇ solid solutions satisfy Vegard's low which confirms the formation of the solid solutions because all the lattice parameters vary linearly throughout the entire composition range. Also, the unit cell volume of the solids solutions was on the order of approximately 713.5 Å³, because the variation in the lattice parameter, a, was symmetric with respect to that in the lattice parameter, b, caused by the Zn substitution for Mg. As mentioned previously, the crystal structure of $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions is composed of the (Mg, Zn)O₄ and SiO₄ tetrahedra as shown in Fig. 4.

The effects of Zn substitution for Mg on the volumes of these tetrahedra in the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions are shown in Fig. 5. Although any remarkable variations in the volume of the SiO_4 tetrahedra were not observed in the composition range of 0–1, the volume in the $(Mg, Zn)O_4$ tetrahedra

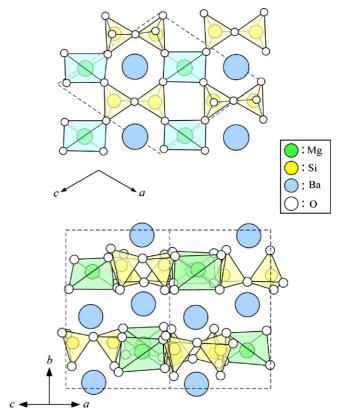


Fig. 2. Schematic diagram of crystal structure of melilite-type $Ba_2MgSi_2O_7$ ceramic.

in the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions was observed to be linear, depending on the composition x; that of the (Mg, Zn)O₄ tetrahedra decreased. Thus, the unit cell volume of the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions is independent of the variations in the (Mg, Zn)O₄ tetrahedra caused by the Zn substitution for Mg. It is also considered that the variations in the atomic distance in the (Mg, Zn)O₄ and MgO₄ tetrahedra caused by the Zn substitution for Mg are associated with the volume of these tetrahedra. Thus, in order to clarify the variations in the atomic distances of (Mg, Zn)O₄ and MgO₄ tetrahedra, they were investigated in this study. In the (Mg, Zn)O₄ tetrahedra, the decreases in oxygen-oxygen distances such as O(2)-O(3'), O(2')-O(3), O(2)–O(2') and O(3)–O(3') bonds were observed with the Zn substitution for Mg. Since the direction of the O(2')–O(3) bond in the (Mg, Zn)O₄ tetrahedra are parallel to that of the a-axis, it is considered that the increase in the lattice parameter, a, as shown in Fig. 3 relates closely with the variations in the atomic distances of the O(2')–O(3) bond.

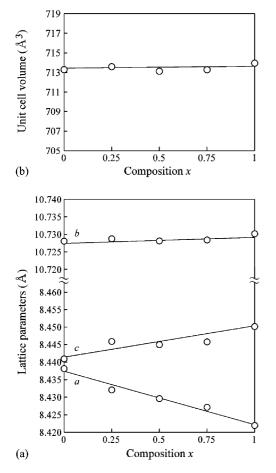


Fig. 3. Variations in (a) lattice parameters and (b) unit cell volume of $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions as a function of composition x.

of the silicates. Moreover, the bond angle of Si–O(4)–Si of the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions increased linearly from 147.5° to 159°, depending on the composition x. Therefore, it is recognized that the bond angle of Si–O(4)–Si in the $[Si_2O_7]^{6-}$ group approaches the bond angle of 180° with increasing the composition x.

Although the volume and the atomic distances of $(Mg,Zn)O_4$ and SiO_4 tetrahedra, and the bond angle of Si-O(4)-Si in the $[Si_2O_7]^{2-}$ group were clarified, the effects of Zn substitution for Mg on the covalency of cation–oxygen bonds have not been investigated; it is expected that these variations in the covalency of cation–oxygen bonds exert an influence on the microwave dielectric properties. ¹⁰ Therefore, the covalencies of cation–oxygen bonds over the whole composition range were

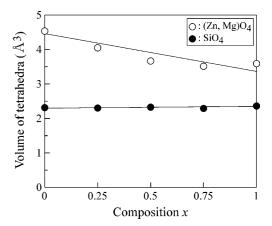


Fig. 5. Effect of Zn substitution for Mg on volume of (Mg, Zn)O $_4$ and SiO $_4$ tetrahedra as a function of composition x.

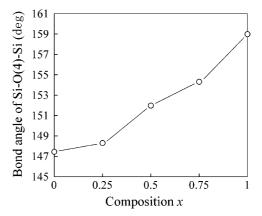


Fig. 6. Variation in bond angle of Si-O(4)-Si in [Si₂O₇]⁶⁻ group as a function of composition x.

calculated by using the refined bond length. The relationship between the covalency and the bond length is given by two equations $^{11-13}$:

$$s = \left(\frac{R}{R_1}\right)^{-N} \tag{1}$$

and

$$f_{c}' = as^{M} \tag{2}$$

where *s* is the bond strength, *R* the refined bond length and R_1 , N, a and M are the empirically determined parameters, which were reported by Brown et al. ^{12,13} The covalencies of Zn–O, Mg–O and Si–O bonds in the (Mg, Zn)O₄ and SiO₄ tetrahedra

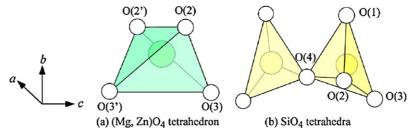


Fig. 4. Schematic representations of (Mg, Zn)O₄ and SiO₄ tetrahedra.

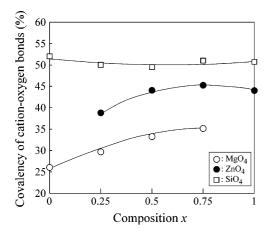


Fig. 7. Effects of Zn substitution for Mg on covalency of cation–oxygen bonds as a function of composition *x*.

caused by the Zn substitution for Mg are shown in Fig. 7. In the case of the MgO₄ tetrahedron, the covalency of the Mg–O bond increased from 26 to 35% in the composition range of 0–0.75. Thus, the increase in the covalency of the Mg-O bond in the MgO₄ tetrahedron is due to the decrease in the bond length of Mg-O(3) and Mg-O(3') bonds caused by the Zn substitution for Mg. The covalency of the Zn–O bond increased in the composition range of 0.25–1, while the covalency of Si–O bonds in the SiO₄ tetrahedron was on the order of approximately 50% over the whole composition range. From these results, it is suggested that the Zn substitution for Mg primarily exerts an influence on the covalency of Mg-O and Zn-O bonds in the (Mg, Zn)O₄ tetrahedra. Also, the increase in the covalency of Mg-O and Zn-O bonds in the (Mg, Zn)O₄ tetrahedra may be attributed to the variation in the bond angle of Si-O(4)-Si in the $[Si_2O_7]^{6-}$ group caused by the Zn substitution for Mg, because the (Mg, Zn)O₄ tetrahedra and [Si₂O₇]⁶⁻ group are composed of shared oxygen atoms. Moreover, the average total covalency of Mg-O, Zn-O and Si-O bonds of the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions is shown in Fig. 8. The average total covalency of these bonds remained the constant value of approximately 46% in the composition range of 0–1. Thus, the variations in the average total covalency of the Mg-O, Zn-O and Si-O bonds of the $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions may be associated with the

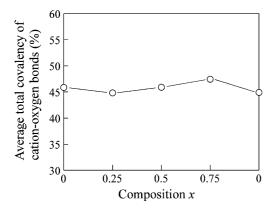


Fig. 8. Variation in average total covalency of Mg—O, Zn—O and Si—O bonds as a function of composition *x*.

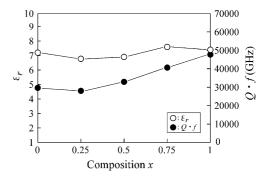


Fig. 9. Variations in ε_r and Qf values of $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions as a function of composition x.

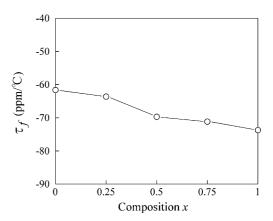


Fig. 10. Temperature dependence of dielectric constant of $Ba_2(Mg_{1-x}Zn_x)$ Si_2O_7 solid solutions as a function of composition x.

microwave dielectric properties caused by the Zn substitution for Mg.

The microwave dielectric properties of $Ba_2(Mg_{1-x}Zn_x)$ Si_2O_7 solid solutions are shown in Figs. 9 and 10. The ε_r values of the solid solutions are on the order of approximately 7.5 in the composition range of 0–1; therefore, the variation in the $\varepsilon_{\rm r}$ values may be correlated with the average total covalency of cation-oxygen bonds caused by the Zn substitution for Mg, because the ε_r and the average total covalency shows a similar tendency in the composition range of 0-1. Moreover, the $Q \cdot f$ values of the solid solutions increased linearly from approximately 30,000 to 48,000 GHz, depending on the composition x. Thus, the highest $Q \cdot f$ value of 48,000 GHz was obtained at x = 1, and the Zn substitution for Mg was effective in improving the $Q \cdot f$ values in this system. The τ_f value of the solid solutions varied from -62 to -74 ppm/°C with increasing the composition x; therefore, the substitution of the other elements in this system is necessary in order to improve the τ_f value.

4. Conclusion

The $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions were prepared and the relationship between the crystal structure and the microwave dielectric properties were investigated in this study. From the Rietveld analysis, it was found that the Zn substitution for Mg in $Ba_2(Mg_{1-x}Zn_x)Si_2O_7$ solid solutions showed a single phase of melilite-type structure over the whole composition range.

The bond angle of Si-O(4)O-Si in the $[Si_2O_7]^{2-}$ group were increased by the Zn substitution for Mg. The covalency of the Mg-O bond in the MgO₄ tetrahedra increased from 26 to 35% in the composition range of 0-0.75, and that of Zn-O bond in the ZnO₄ tetrahedra also increased in the composition range of 0.25–1. On the other hand, the covalency of the Si–O bond in the SiO₄ tetrahedron remained the constant value of approximately 50% over the whole composition range. From the results of the covalency of cation-oxygen bonds in the (Mg, Zn)O₄ and SiO₄ tetrahedra, the average total covalency of cation-oxygen bonds in the (Mg, Zn)O₄ and SiO₄ tetrahedra remain unaltered over the whole composition range. The dielectric constants of the solid solutions are on the order of approximately 7.5; therefore, the dielectric constant of the solid solutions may be attributed to the average total covalency of Mg-O, Zn-O and Si-O bonds of the Ba₂(Mg_{1-x}Zn_x)Si₂O₇ solid solutions. Moreover, the $Q \cdot f$ values of the solid solutions are increased by the Zn substitution for Mg; therefore, it is recognized that the Zn substitution for Mg is effective in improving the $Q \cdot f$ value in this system. The $\tau_{\rm f}$ values of the solid solutions in the composition range of 0–1 vary from -62 to -74 ppm/°C; therefore, the substitution of the other elements in this system is necessary in order to improve the τ_f values.

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